

# **NCE Automotive P-Channel Super Trench Power MOSFET**

### **Description**

The NCEAP40P60G uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification

## **Application**

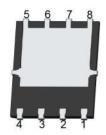
- Automotive application
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

### **General Features**

- $V_{DS}$  =-40V, $I_D$  =-60A  $R_{DS(ON)}$ =8.8mΩ (typical) @  $V_{GS}$ =-10V  $R_{DS(ON)}$ =12.5mΩ (typical) @  $V_{GS}$ =-4.5V
- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested
- 100% ΔVds tested
- AEC-Q101 qualified

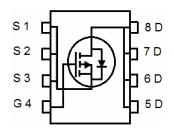
### **DFN 5X6**





**Top View** 

**Bottom View** 



**Schematic Diagram** 

# **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
AP40P60G	NCEAP40P60G	DFN5X6-8L	-	-	-

## Absolute Maximum Ratings (T<sub>C</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	-40	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I <sub>D</sub> (T <sub>C</sub> =25℃)	-68	А
Drain Current-Continuous(T <sub>C</sub> =100°C)	I <sub>D</sub> (T <sub>C</sub> =100°C)	-48.6	А
Pulsed Drain Current	I <sub>DM</sub>	-272	Α
Maximum Power Dissipation(T <sub>C</sub> =25 ℃)	P <sub>D</sub> (T <sub>C</sub> =25°C)	96	W
Derating factor		0.64	W/℃
Single pulse avalanche energy (Note 1)	E <sub>AS</sub>	352	mJ
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 175	°C

### **Thermal Characteristic**

Thermal Resistance,Junction-to-Case	Rejc	1.56	°C/W
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# NCEAP40P60G

# Electrical Characteristics (Tc=25°C unless otherwise noted)

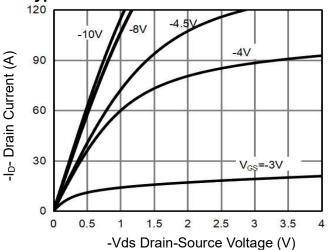
Parameter	Symbol	Condition	Min	Тур	Max	Unit		
Off Characteristics								
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250μA	-40	-	-	V		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	I <sub>DSS</sub> V <sub>DS</sub> =-40V,V <sub>GS</sub> =0V		-	1	μA		
Gate-Body Leakage Current	Igss	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA		
On Characteristics								
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS},I_{D}=-250\mu A$	-1.1	-1.7	-2.2	V		
Dunin Sauras On State Besietenes		V <sub>GS</sub> =-10V, I <sub>D</sub> =-20A	-	8.8	11.0	mΩ		
	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-20A	-	12.5	17.0	mΩ			
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =-5V,I <sub>D</sub> =-20A	-	30	-	S		
Dynamic Characteristics								
Input Capacitance	C <sub>lss</sub>	\\ 00\\\\ 0\\	-	2450	-	pF		
Output Capacitance	Coss	V <sub>DS</sub> =-20V,V <sub>GS</sub> =0V,	-	660	-	pF		
Reverse Transfer Capacitance	Crss	F=1.0MHz	-	18	-	pF		
Switching Characteristics (Note 2)	·							
Turn-on Delay Time	t <sub>d(on)</sub>		-	9	-	nS		
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =-20 $V$ , $I_{D}$ =-20 $A$	-	4	-	nS		
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =-10 $V$ , $R_{G}$ =1.6 $\Omega$	-	30	-	nS		
Turn-Off Fall Time	t <sub>f</sub>		-	5	-	nS		
Total Gate Charge	$Q_g$	V 00V/1 00A	-	39	-	nC		
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =-20V, $I_{D}$ =-20A,	-	7.8		nC		
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =-10V	-	5.3		nC		
Drain-Source Diode Characteristics								
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =-20A	-	-	-1.2	V		
Diode Forward Current	Is		-	-	-68	Α		
Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> = 25°C, I <sub>F</sub> =-20A	-	22	-	nS		
Reverse Recovery Charge	Qrr	di/dt = 100A/μs	-	58	-	nC		

## Notes:

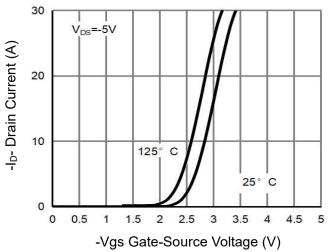
- 1. EAS condition : Tj=25  $^{\circ}\text{C}$  ,VDD=-20V,VG=-10V,L=0.5mH,Rg=25 $\Omega$
- 2. Guaranteed by design, not subject to production
- 3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of TJ(MAX)=175°C. The SOA curve provides a single pulse rating.



# **Typical Electrical and Thermal Characteristics**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

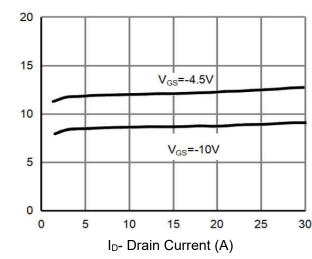


Figure 3 Rdson- Drain Current

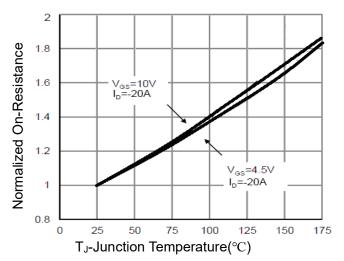


Figure 4 Rdson-JunctionTemperature

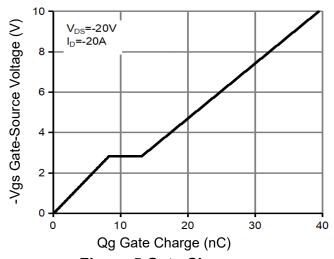


Figure 5 Gate Charge

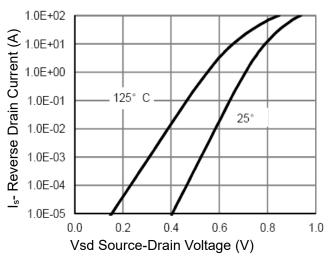


Figure 6 Source- Drain Diode Forward



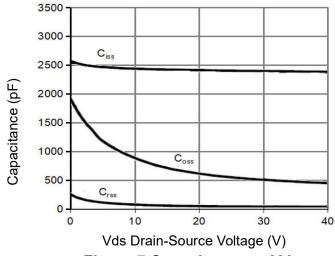


Figure 7 Capacitance vs Vds

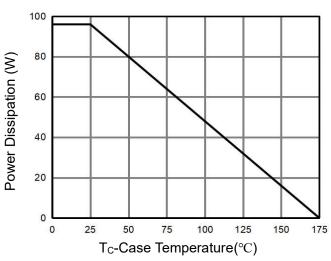


Figure 9 Power De-rating

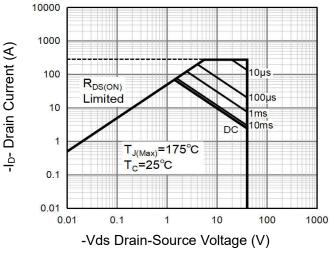


Figure 8 Safe Operation Area (Note 3)

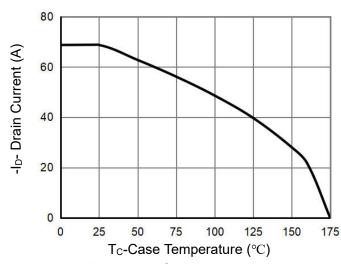


Figure 10 Current De-rating

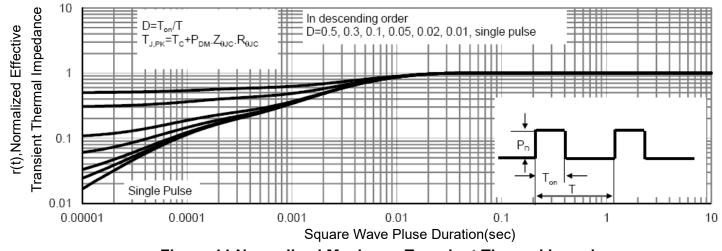
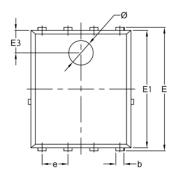


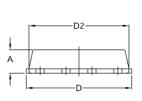
Figure 11 Normalized Maximum Transient Thermal Impedance

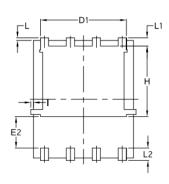


# **DFN5X6-8L Package Information**









S Y	COMMON					
M B	M	IM	INCH			
O L	MIN.	MAX.	MIN.	MAX.		
Α	1.03	1.17	0.0406	0.0461		
b	0.34	0.48	0.0134	0.0189		
С	0.15	0.30	0.0059	0.0118		
D	4.80	5.40	0.1890	0.2126		
D1	4.11	4.31	0.1618	0.1697		
D2	4.80	5.00	0.1890	0.1969		
Е	5.95	6.15	0.2343	0.2421		
E1	5.65	5.85	0.2224	0.2303		
E2	1.40	_	0.0551	_		
E3	1.00	1.20	0.0394	0.0472		
е	1.27	BSC	0.05	BSC		
L	0.05	0.25	0.0020	0.0098		
L1	0.38 0.50 0.015		0.0150	0.0197		
L2	0.38	0.71	0.0150	0.0280		
Н	3.30	3.50	0.1299	0.1378		
I	_	0.18	_	0.0070		
Ø	1.10	1.30	0.0433	0.0512		



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